



LI DE HENG ELECTRONICS

BAS70WS

SOD-323 Plastic-Encapsulate Diodes

**BAS70WS** SCHOTTKY DIODES**FEATURES**

- LOW Turn-on Voltage
- Fast Switching
- PN Junction Guard for Transient and ESD Protection
- Designed for Surface Mount Application
- Plastic Material –UL Recognition Flammability Classification 94V-O

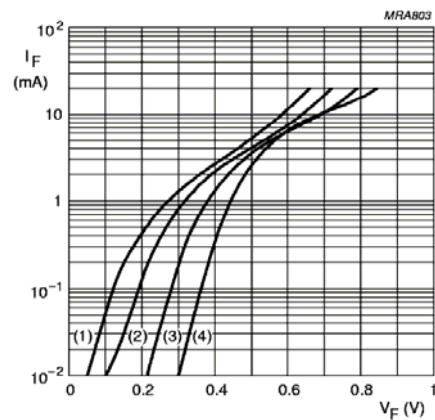
SOD-323

**Maximum Ratings and Electrical Characteristics, Single Diode @T<sub>A</sub>=25**

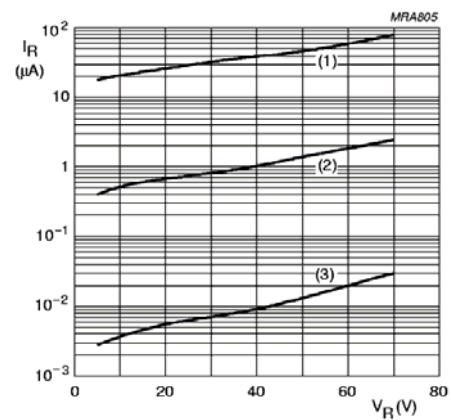
Parameter Symbol		Limits	Unit
<b>Peak Repetitive Peak reverse voltage</b>	V <sub>RRM</sub>		
<b>Working Peak Reverse Voltage</b>	V <sub>RWM</sub>	70	V
<b>DC Blocking Voltage</b>	V <sub>R</sub>		
<b>Forward Continuous Current</b>	I <sub>F</sub>	70	mA
<b>Peak forward surge current @&lt;1.0s</b>	I <sub>FSM</sub>	100	mA
<b>Power Dissipation</b>	P <sub>d</sub>	200	mW
<b>Thermal Resistance Junction to Ambient</b>	R <sub>θJA</sub>	625	°C/W
<b>Storage temperature</b>	T <sub>STG</sub>	-55 to +150	°C

**Electrical Ratings @T<sub>A</sub>=25°C**

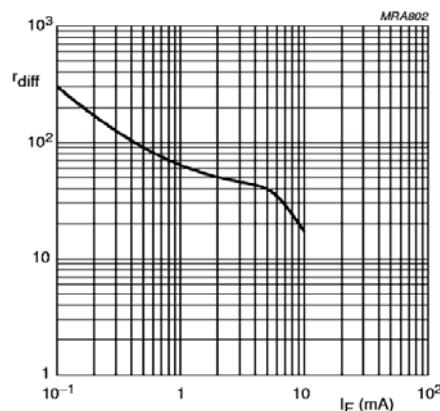
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
<b>Forward voltage</b>	V <sub>F1</sub>			0.41	V	I <sub>F</sub> =1mA
	V <sub>F2</sub>			1	V	I <sub>F</sub> =15mA
<b>Reverse current</b>	I <sub>R</sub>			120	nA	V <sub>R</sub> =50V
<b>Capacitance between terminals</b>	C <sub>T</sub>			2	pF	V <sub>R</sub> =0V,f=1MHz
<b>Reverse Recovery Time</b>	t <sub>rr</sub>			5	ns	I <sub>F</sub> =I <sub>R</sub> =10mA I <sub>rr</sub> =0.1XI <sub>R</sub> ,R <sub>L</sub> =100Ω

**Typical Characteristics****BAS70W S**

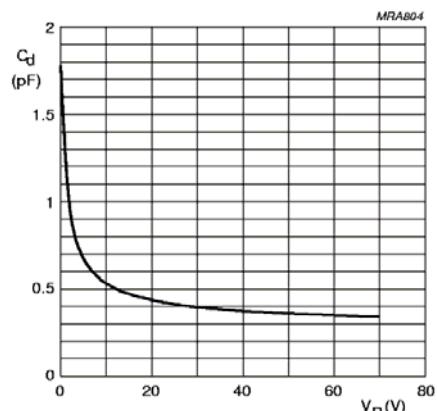
Forward current as a function of forward voltage; typical values.



Reverse current as a function of reverse voltage; typical values.

 $f = 10\text{ kHz}$ .

Differential forward resistance as a function of forward current; typical values.

 $f = 1\text{ MHz}; T_{amb} = 25\text{ }^{\circ}\text{C}$ .

Diode capacitance as a function of reverse voltage; typical values.